K ondo and D icke e ect in quantum -dots side coupled to a quantum wire

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Electron tunneling through quantum—dots side coupled to a quantum wire, in equilibrium and nonequilibrium K ondo regime, is studied. The mean—eld nite-U slave-boson formalism is used to obtain the solution of the problem. We have found that the transmission spectrum shows a structure with two anti-resonances localized at the renormalized energies of the quantum dots. The DOS of the system shows that when the K ondo correlations are dominant there are two K ondo regimes with its own K ondo temperature. The above behavior of the DOS can be explained by quantum interference in the transmission through the two dierent resonance states of the quantum dots coupled to common leads. This result is analogous to the Dickee ect in optics. We investigate the many body K ondo states as a function of the parameters of the system.

I. INTRODUCTION

The K ondo e ect in quantum dots (QDs) has been extensively studied in the last years 1,2,3. The QDs allow studying system atically the quantum—coherence manybody K ondo state, due to the possibility of continuous tuning the relevant parameters governing the properties of this state, in equilibrium and nonequilibrium situations. Recently K ondo e ect has been studied in side attach quantum dot 4 and parallel quantum dots 1. Recent electron transport experiments showed that K ondo and Fano resonances occur simultaneously 5. Multiple scattering of traveling electronic waves on a localized magnetic state are crucial for the form ation of both resonances. The condition for the Fano resonance is the existence of two scattering channels: a discrete level and a broad continuum band 6.

An alternative con guration consists of two single QDs side attached to a perfect quantum wire (QW). This structure is rem iniscent of the cross-bar-shaped quantum wave guides 7 . In this case, the QDs act as scattering centers in close analogy with the traditional K ondo e ect 8 . This con guration was study previously by Stefanski 11 and Tamura et at 12 .

In this work we study the transport properties of two single quantum dots side coupled to a quantum wire in the K ondo regime. We use the nite-U slave boson meaneld approach, which was initially developed by Kotliar and Ruckenstein 13 and used later by Bing Dong and X.L. Lei to study the transport through coupled double quantum dots connected to leads 14. This approach enforces the correspondence between the impurity ferm ions and the auxiliary bosons to a mean-eld level to release the U = 1 restriction. In quantum dots, this approach allows to treat the dot-lead coupling nonperturbatively for an arbitrary strength of the Coulomb interaction U 14. We have found that the transmission spectrum shows a structure with two anti-resonances localized at the renormalized energies of the quantum dots. The DOS of the system shows that when the K ondo correlations are dominant there are two Kondo regimes each with its own

K ondo tem perature. The above behavior of the DOS can be explained by quantum interference in the transm ission through the two di erent resonance states of the quantum dots coupled to common lead. This phenomenon is in analogy to the Dicke e ect in quantum optics, that takes place in the spontaneous emission of two closelylying atoms radiating a photon into the same environment entle. In the electronic case, however, the decay rates (level broadening) are produced by the indirect coupling of the up-down QDs, giving rise to a fast (superradiant) and a slow (subradiant) mode. Recently, Brandes reviewed the Dicke e ect in mesoscopic systems 17 .

II. M ODEL

Let us consider two single quantum dot (2QD) side coupled to a perfect quantum wire (QW) (see Fig.1). We adopt the two-im purities Anderson Ham iltonian. Each dot has a single level energy "1 (with 1 = 1;2), and a intra-dot C oulom b repulsion U. The two side attached quantum dots are coupled to the QW with coupling t0. The QW sites have local energies "wi; = 0 and a hopping param eter t.

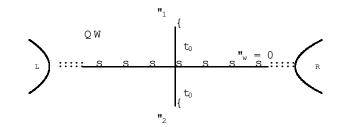


FIG.1: Scheme of side-coupled quantum dots attached laterally to a perfect quantum wire (QW). The QW is coupled to the left (L) and right (R) non-interacting leads.

The corresponding Hamiltonian model is,

where c_{i}^{y} , $(c_{i}$;) is the creation (annihilation) operator of an electron with spin at the i-th site of the quantum wire; $f_{1;}^{y}$ ($f_{1;}$) is the creation (annihilation) operator of an electron with spin in the 1th QD and fil; is the corresponding number operator.

To nd the solution of this correlated ferm ions system, we appeal to an analytical approach where, generalizing the in nite-U slave-boson approximation 18 the Hilbert space is enlarged at each site, to contain in addition to the original ferm ions a set of four bosons 13 represented by the creation (annihilation) operators e_1^y (e_1), $p_{1;}^y$ (p_1 ;), and d_1^y (d₁) for the 1-th dot. I hey act as projectors onto empty, single occupied (with spin up and down) and doubly occupied electron states, respectively. Then, each creation (annihilation) operator of an electron with spin in the Ith QD, is substituted by $f_{1;}^{y}$ $\mathcal{Z}_{1;}^{y}$ ($\mathcal{Z}_{1;}$ $f_{1;}$) where:

$$Z_{1;} = \frac{e_{1}^{y}p_{1;} + p_{1;}^{y}}{1 \quad \dot{q}'d_{1} \quad \dot{p}'_{1}, p_{1;}} \frac{d_{1}}{1 \quad \dot{e}'e_{1} \quad \dot{p}'_{1}, p_{1;}}$$
 (2)

The denominator is chosen to reproduce the correct U! 0 lim it in the mean-eld approximation without changing neither the eigenvalues nor the eigenvector.

P The constraint, i.e., the completeness relation p_{l}^{y} , p_{l} , p_{l} , + $b_{l}^{y}b_{l}$ + $d_{l}^{y}d_{l}$ = 1 and the condition among ferm ions and bosons n_1 ; p_1 ; p_1 ; $\dot{\mathbf{q}} d_1 = 0$, will be incorporated with Lagrange multipliers $_{1}^{(1)}$ and $_{1}^{(2)}$ into the Hamiltonian. Also in the mean-eld approximation all the boson operators are replaced by their expectation value which can be chosen, without loss of generality, as real num bers.

The Hamiltonian in this new and enlarged Hilbert space, is, $H = H_b + H_e$, where

$$H_{b} = \begin{array}{c} X \\ 1 \\ 1 \end{array} p_{1;"}^{2} + p_{1;\#}^{2} + e_{1}^{2} + d_{1}^{2} & 1 \\ X \\ 1; p_{1;}^{2} + d_{1}^{2} + U \\ 1; p_{1;}^{2} + d_{1}^{2} + U \\ 1; p_{1;2}^{2}; \end{array} (3)$$

depends explicitly only upon the boson expectation values and the Lagrange multipliers, and

is a tight-binding Hamiltonian that depends implicitly on the boson expectation values through the param eters: $\mathbf{u}_{1;} = \mathbf{u}_{1;} + \frac{(2)}{1;}, t_{1;} = t_0 h \mathbf{Z}_{1;} i.$

As we work at zero tem perature, the boson operators expectation values and the Lagrange multipliers are determ ined by m in im izing the energy hH i with respect to these quantities. It is obtained in this way, a set of nonlinear equations for each quantum dot, relating the expectation values of the four bosonic operators, the three Lagrange multipliers and the electronic expectation val-

$$p_{1;}^{2} = h\hat{n}_{1;} i d_{1;}^{2};$$
 (5a)
 $e_{1}^{2} = 1 h\hat{n}_{1;s}i + d_{1}^{2};$ (5b)

$$e_1^2 = 1$$
 $hh_{1;s}i + d_1^2;$ (5b)

$$_{1}^{(1)} = \frac{t_{0}}{e_{1}}^{X} \quad hf_{1;s}^{y}c_{0;s}i\frac{\theta h\mathcal{Z}_{1;s}i}{\theta e_{1}};$$
 (5c)

$$\begin{array}{ccc}
 & (1) & & (2) \\
 & 1; & = \frac{t_0}{p_{1;}} & & \text{hf}_{1;s}^{y} c_{0;s} i \frac{\theta h \sum_{1;s} i}{\theta p_{1;}}; & (5d)
 \end{array}$$

$$U + {\begin{pmatrix} 1 \\ 1 \end{pmatrix}} X \qquad {\begin{pmatrix} 2 \\ 1;s \end{pmatrix}} = \frac{t_0}{d_1} X \qquad hf_{1;s}^{y} c_{0;s} i \frac{@hZ_{1;s}i}{@d_1} : \qquad (5e)$$

where listhe dotindex, s, are spin indexes and hZl;si satis es,

$$hT_{1;s}i = \frac{p_{1;s} (e_1 + d_1)}{1 + q^2 + p^2_{1;s} + 1 + q^2 + p^2_{1;s}}; \quad (6)$$

To obtain the electronic expectation values h Hamiltonian, He, is diagonalized and their stationary states can be written as

$$j_{k}i = \begin{cases} x^{k} & x^{2} \\ a_{j}^{k} j j i + b_{1}^{k} j i ; \end{cases}$$
 (7)

where a_i^k and b_i^k are the probabilities amplitudes to nd the electron at the site j and at the 1-th QD respectively, with energy! = 2tcosk. As we study the param agnetic case the spin index is neglected.

The amplitudes a_i^k and b_l^k obey the following linear di erence equations

$$! a_{i}^{k} = t(a_{i+1}^{k} + a_{i+1}^{k}); j \in 0;$$
 (8a)

$$!a_0^k = t(a_1^k + a_1^k) t_1b_1^k t_2b_2^k;$$
 (8b)

$$(! \quad I_1)b_1^k = t_1a_0^k;$$
 (8c)

In order to study the solutions of Eqs. (8), we assume that the electrons are described by a unitary incident amplitude plane wave and rejection and transmission amplitudes r and respectively. That is,

$$a_{j}^{k} = e^{ik} + re^{ik}; (k j < 0);$$
 (9a)

$$a_{j}^{k} = e^{ik j}$$
 ; (k j > 0): (9b)

Inserting Eqs. (9) into Eqs. (8), we get an inhomogeneous system of linear equations for , r, a_j^k and b_l^k , leading to the following expression in equilibrium

$$= \frac{1}{1 + i(\frac{\tilde{n}_1}{1 + \tilde{n}_1} + \frac{\tilde{n}_2}{1 + \tilde{n}_2})};$$
 (10)

where $^{\sim}_{1}=$ t_{1}^{2} $_{0}$ (!) (l=1;2) is the renormalized coupling between each quantum-dot and the leads of density of states $_{0}$ (!). In spite of the apparent simplicity of the expression, it is necessary remember that the quantity t_{1} implicitly depends on the expectation values of the boson operators also as ferm ion operators.

The transm ission probability is given by $T = j \hat{j}$,

$$T (!) = \frac{1}{1 + (\frac{\tilde{1}}{1 + \tilde{1}} + \frac{\tilde{2}}{1 + \tilde{1}})^{2}} :$$
 (11)

From the amplitudes b_1^k and b_2^k we obtain the local density of states (LDOS) at the quantum dot 1 (with l=1;2). In equilibrium that is,

$$_{1}(!) = \frac{1}{\tilde{1}} \frac{(\frac{\tilde{1}}{1 + \tilde{1}})^{2}}{1 + (\frac{\tilde{1}}{1 + \tilde{1}} + \frac{\tilde{1}}{1 + \tilde{1}})^{2}} : \tag{12}$$

In the nonequilibrium case, we suppose a nite source-drain biased with a sym metric voltage drop. The incident electrons from the left side (L), they are in equilibrium with thermodynamical potential $_{\rm L}$ = V=2, and the incidents from the right side (R), they are in equilibrium with thermodynamical potential $_{\rm R}$ = V=2.

O noe the amplitudes a_{j}^k , and b_{j}^k , are known, the electronic expectation values is obtained from,

And the current is obtained from ,

$$J = 2 \frac{2e}{r} t^{X}$$
 f (_k) Im fa_{0}^{k} a_{1}^{k} g (14)

where f ($_{k}$) it is the Ferm i function for incident electrons from the side.

III. RESULTS

We solve numerically the set of nonlinear equations and take typical values for the parameters that dene the system, t=25, $t_0=5$ where $=t_0^2$ (0) is taken to be the unit of energy.

W e consider $\,$ rst the situation in equilibrium $\,$ where the two dots local state energies are set by $\textbf{"}_1=V_g~~V$, and $\textbf{"}_2=V_g+~V$. W e choose the value of $V_g=~3~$. From now on all energies in units of .

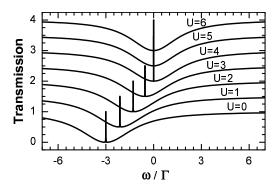


FIG. 2: Transm ission spectrum in equilibrium for $V_g = 3$, V = 0.1 and various values of U.

The transm ission probability, T, is displayed in Fig. 2 for various values of U. The transm ission probability always reaches zero at ! = \mathbf{u}_1 and \mathbf{u}_2 and unitary value at ! = $(\mathbf{u}_1 + \mathbf{u}_2)$ =2. For small values of U the anti-ferrom agnetic spin-spin correlation between the dots is dominant and the system does not posses a K ondo regim e^{15} . Increasing U, a sharp feature develops close to the Ferm i energy (! = 0), indicating the appearance of a K ondo resonance.

For U su ciently large the transm ission can be written approxim ately as the superposition of a Fano and a Briet-W igner line shapes,

T (!)
$$\frac{(+q)^2}{2+1} + \frac{^2}{12+^2};$$
 (15)

where = $!=2^{\sim}$, q=0, with $\sim= \nabla^2=2^{\sim}$.

The DOS gives us more details about the form ation of the Kondo resonance. The DOS is displayed in Fig. 3. In the Kondo regime the DOS can be written as the superposition of the two Lorentzian. These results in ply

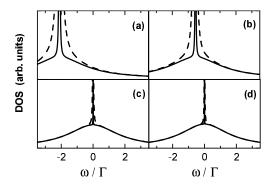


FIG .3: DOS for $V_g=3$, V=0.1 (solid line), 0.5 (dashed line). The on site energy U , is (a) 1, (b) 3, (c) 5 and (d) 6.

the existence of two K ondo tem perature $T_{1K}=2^{\circ}$ and $T_{2K}=^{\circ}=7$, associated to each K ondo regim e.

(!)
$$\frac{1}{1!^2 + 4^2} + \frac{1}{1!^2 + 2}$$
: (16)

The above behavior of the DOS is due to quantum interference taking place in the transmission through the two di erent discrete states (the two quantum -dot levels) coupled to common leads. This phenomenon resembles the Dicke e ect in optics, which takes place in the spontaneous em ission of a pair of atom s radiating a photon with a wave length much larger than the separation between them . 16 The lum inescence spectrum is characterized by a narrow and a broad peak, associated with long and short-lived states, respectively. The former state, weakly coupled to the electrom agnetic eld, is called subradiant, and the latter, strongly coupled, superradiant state. In the present case this e ect is due to the indirect coupling between up-down QDs through the QW. The states strongly coupled to the QW yield an e ective width 2~ while those weakly coupled to the QW give a Dicke state with width ~. A similar result was found for a parallel double quantum dot without electron-electron interaction.²⁰

The current and the di erential conductance dJ=dV are two signi cant and experim entally measured quantities, which have been calculated numerically at nite source-drain biases.

Figure 4 displays the characteristic J V (solid line) and the differential conductance dJ=dV-V (dashed line) for two values of V. For V=0.1 the current shows a pronounced plateau around zero bias while for V=0.5 the plateau is less defined. However in both cases the differential conductance shows an anomaly at zero bias.

Figure 5 shows details of the current and di erential conductance around zero bias.

We can obtain the expressions for the current and the dierential conductance by integrating over! the transmission probability given in Eq. (15).

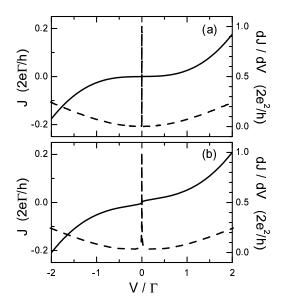


FIG. 4: Current (solid line) and dierential conductance (dashed line) for $V_g=3$, on site energy, U=6 for a) V=0.1 and b) V=0.5

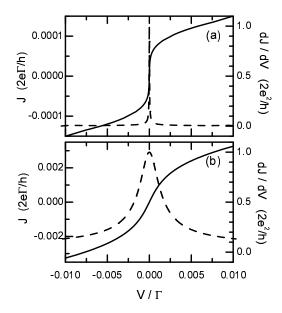


FIG. 5: Current (solid line) and D i erential conductance (dashed line) for $V_g=\ 3$, on site energy, U = 6 for a) V=0.1 and b) V=0.5

J
$$\frac{2e}{h}$$
 V 2° arctan $\frac{V}{2^{\circ}}$ + °arctan $\frac{V}{\sim}$;
 $\frac{eJ}{eV}$ $\frac{2e^{2}}{h}$ 1 $\frac{4^{\circ 2}}{\frac{V}{2}^{2} + 4^{\circ 2}}$ + $\frac{c^{2}}{\frac{V}{2}^{2} + c^{2}}$; (17)

We identify each term of the above equation as follows.

The rst term in the right side of the Eqs.(17) is the contribution arising from an ideal unidim ensional conductor. The second term comes from the K ondo-Fano state with temperature T_{1k} giving a quasiplateau for the current and almost zero dierential conductance when y = 7. The third term arises from the K ondo-D icke state weakly coupled to the wire. It is responsible for an abrupt increase of the current and an amplication on the dierential conductance around zero bias. Finally, for y > 7, K ondo e ect disappears.

IV. SUMMARY

We have studied the transport through two single side-coupled quantum dots using the nite-U slave boson mean eld approach at T=0. We have found that the transmission spectrum shows a structure with two anti-resonances localized at the renormalized energies of

the quantum dots. The DOS of the system shows that when the K ondo correlations are dominant there are two K ondo regimes each with its own K ondo temperature. The above behavior of the DOS is due to quantum interference in the transmission through the two dierent resonance states of the quantum dots coupled to common leads. This result is analogous to the Dicke e ect in optics. These phenomena have been analyzed as a function of the relevant parameters of the system.

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